

Static Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
V _{(BR)DSS}	Drain-to-Source Breakdown Voltage	100			V	$V_{GS} = 0V, I_D = 250\mu A$
$\Delta V_{(BR)DSS}/\Delta T_J$	Breakdown Voltage Temp. Coefficient		0.122		V/°C	Reference to 25°C, I _D = 1mA
				0.105	Ω	V _{GS} = 10V, I _D = 10A ④
R _{DS(on)}	Static Drain-to-Source On-Resistance			0.125		$V_{GS} = 5.0V, I_D = 10A $ ④
				0.155		$V_{GS} = 4.0V, I_D = 9.0A$ ④
V _{GS(th)}	Gate Threshold Voltage	1.0		2.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
gfs	Forward Transconductance	7.7			S	$V_{DS} = 25V, I_D = 9.0A$ (5)
I _{DSS}	Drain-to-Source Leakage Current			25	μA	$V_{DS} = 100V, V_{GS} = 0V$
				250		$V_{DS} = 80V, V_{GS} = 0V, T_{J} = 150^{\circ}C$
I _{GSS}	Gate-to-Source Forward Leakage			100	nA	V _{GS} = 16V
	Gate-to-Source Reverse Leakage			-100		V _{GS} = -16V

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
Q_g	Total Gate Charge	_		34		$I_D = 9.0A$
Q _{gs}	Gate-to-Source Charge			4.8	nC	$V_{DS} = 80V$
Q_{gd}	Gate-to-Drain ("Miller") Charge	_	_	20		V _{GS} = 5.0V @⑤
t _{d(on)}	Turn-On Delay Time		7.2	_		$V_{DD} = 50V$
t _r	Rise Time	_	53	_	1	$I_{D} = 9.0A$
t _{d(off)}	Turn-Off Delay Time		30		ns	$R_G = 6.0 \Omega$
t _f	Fall Time		26	_		V _{GS} = 5.0V 4 5
L _D	Internal Drain Inductance		4.5			Between lead,
					nH	6mm (0.25in.)
L _S	Internal Source Inductance		7.5			from package
						and center of die contact
C _{iss}	Input Capacitance		800			$V_{GS} = 0V$
C _{oss}	Output Capacitance		160			$V_{DS} = 25V$
C _{rss}	Reverse Transfer Capacitance		90		pF	<i>f</i> = 1.0MHz ⑤

Diode Characteristics

	Parameter	Min.	Тур.	Max.	Units	Conditions	
I _S	Continuous Source Current			17		MOSFET symbol	
	(Body Diode)				Α	showing the	
I _{SM}	Pulsed Source Current			60		integral reverse	
	(Body Diode) ①					p-n junction diode.	
V_{SD}	Diode Forward Voltage			1.3	V	$T_J = 25^{\circ}C$, $I_S = 9.0A$, $V_{GS} = 0V$ ④	
t _{rr}	Reverse Recovery Time		140	210		$T_J = 25^{\circ}C, I_F = 9.0A$	
Q _{rr}	Reverse Recovery Charge		740	1100	nC	di/dt = 100A/µs ⊕⑤	
t _{on}	Forward Turn-On Time	Intrinsion	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

- ① Repetitive rating; pulse width limited by max. junction temperature. (See fig.11)
- ? $V_{DD} = 25V$, starting $T_J = 25^{\circ}C$, L = 3.1mH $R_G = 25\Omega$, $I_{AS} = 9.0A$. (See Figure 12)
- $\ensuremath{ \Im \ I_{SD}} \leq 9.0A, \ di/dt \leq 540A/\mu s, \ V_{DD} \leq V_{(BR)DSS}, \ T_J \leq 175^{\circ}C$
- ④ Pulse width \leq 300µs; duty cycle \leq 2%.
- ⑤ Uses IRL530N data and test conditions.

- $\ensuremath{\texttt{\textcircled{o}}}$ This is applied for L_S of D-PAK is measured between lead and center of die contact
- ⑦ When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994.
- ® R_θ is measured at Tj approximately 90°C.



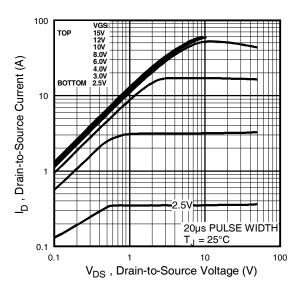


Fig 1. Typical Output Characteristics

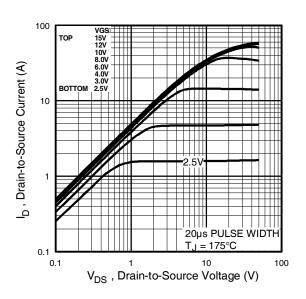


Fig 2. Typical Output Characteristics

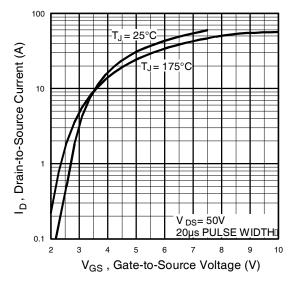


Fig 3. Typical Transfer Characteristics

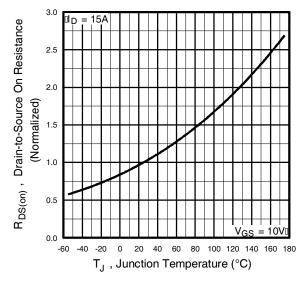


Fig 4. Normalized On-Resistance Vs. Temperature



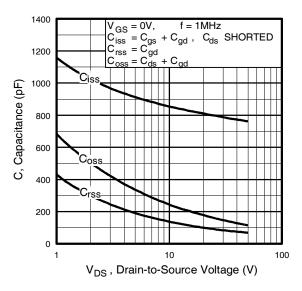


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

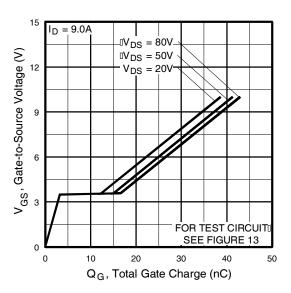


Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage

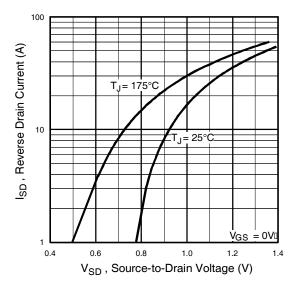


Fig 7. Typical Source-Drain Diode Forward Voltage

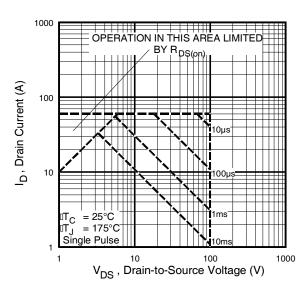


Fig 8. Maximum Safe Operating Area



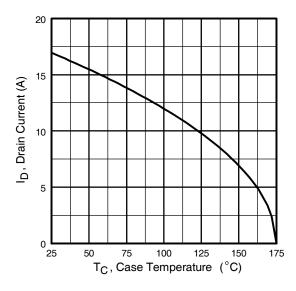


Fig 9. Maximum Drain Current Vs. Case Temperature

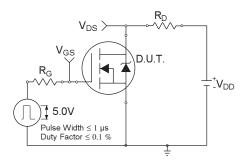


Fig 10a. Switching Time Test Circuit

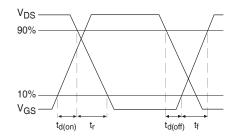


Fig 10b. Switching Time Waveforms

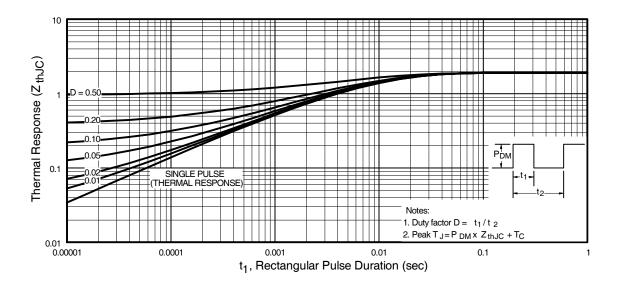


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case



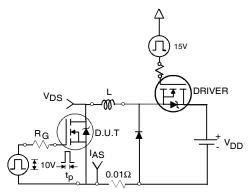


Fig 12a. Unclamped Inductive Test Circuit

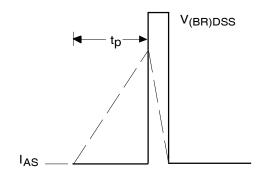


Fig 12b. Unclamped Inductive Waveforms

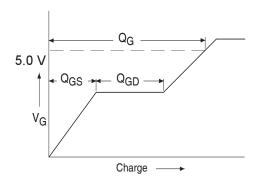


Fig 13a. Basic Gate Charge Waveform

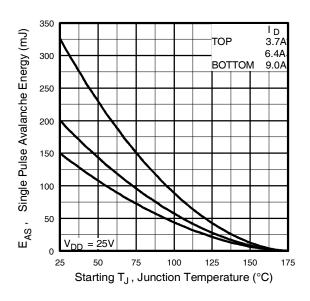


Fig 12c. Maximum Avalanche Energy Vs. Drain Current

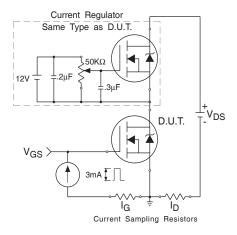
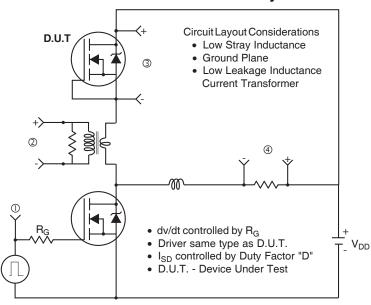
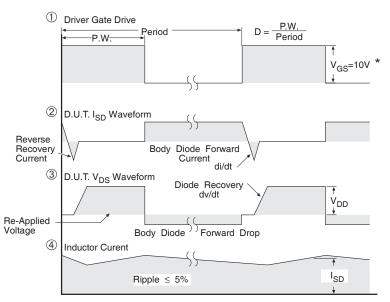


Fig 13b. Gate Charge Test Circuit



Peak Diode Recovery dv/dt Test Circuit





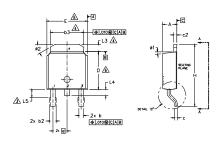
* V_{GS} = 5V for Logic Level Devices

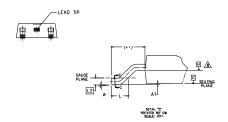
Fig 14. For N-Channel HEXFETS

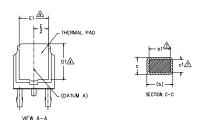


D-Pak (TO-252AA) Package Outline

Dimensions are shown in millimeters (inches)







- 2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS].
- A- LEAD DIMENSION UNCONTROLLED IN L5.

- 25- LEAD DIMENSION UNCONINCILLED IN LS.

 DIMENSION DI, EL, LS & SS ESTABLISH A MINIMUM MOUNTING SURFACE FOR THERMAL PAD.

 5.- SECTION C-C DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 AND 0.10

 [0.13 AND 0.25] FROM THE LEAD TIP.

 DIMENSION D & E DO NOT INCLUDE WOLD FLASH, MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
- SIDE. THESE DIMENSIONS ARE MEASURED AT THE COUNTY

 DIVENSION BY & C1 APPLIED TO BASE METAL ONLY.

 BY DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
- 9.- DUTLINE CONFORMS TO JEDEC OUTLINE TO-252AA,

5		
Y	DIMENSIONS	N
M		~

5 Y		N				
S Y M B	MILLIM	ETERS	INC	O T E S	l	
O L	MIN.	MAX.	MIN.	MAX.	E S	l
Α	2.18	2.39	.086	.094		l
A1	-	0.13	-	.005		ı
ь	0.64	0.89	.025	.035		l
ь1	0.65	0.79	.025	.031	7	ı
b2	0.76	1.14	.030	.045		ı
b3	4.95	5,46	.195	.215	4	ı
c	0.46	0,61	.018	.024		l
c1	0,41	0.56	.016	.022	7	l
c2	0.46	0.89	.018	.035		l
D	5,97	6.22	.235	.245	6	l
D1	5,21	- 1	.205	-	4	l
Ε	6.35	6.73	.250	.265	6	l
E1	4.32	-	.170	-	4	l
e	2.29	BSC	.090	.090 BSC		l
н	9.40	10.41	.370	.410		ı
L	1.40	1.78	.055	.070		l
L1	2.74	2.74 BSC		REF.		l
L2	0,51	BSC	.020	BSC		l
L3	0.89	1.27	.035	.050	4	l
L4	-	1.02	-	.040		l
L5	1,14	1.52	.045	.060	3	l
ø	0.	10*	0.	10*		l
ø1	0,	15"	0,	15*		l
ø2	25*	35*	25*	35*		

LEAD ASSIGNMENTS

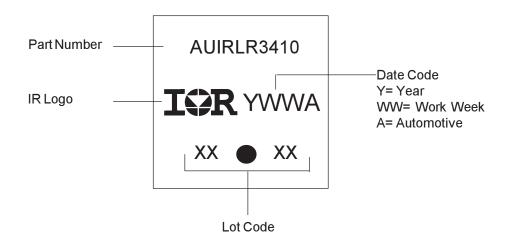
HEXFET

- 1.- GATE 2.- DRAIN 3.- SOURCE 4.- DRAIN

IGBT & CoPAK

- 1.- GATE 2.- COLLECTOR 3.- EMITTER 4.- COLLECTOR

D-Pak Part Marking Information

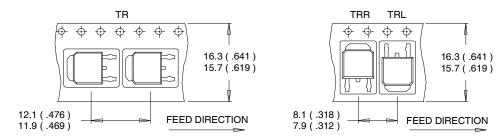


Note: For the most current drawing please refer to IR website at http://www.irf.com/package/



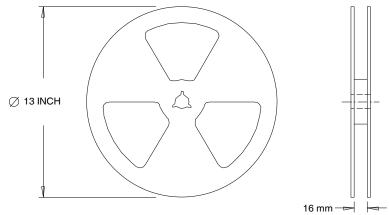
D-Pak (TO-252AA) Tape & Reel Information

Dimensions are shown in millimeters (inches)



NOTES:

- 1. CONTROLLING DIMENSION: MILLIMETER.
- 2. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
- 3. OUTLINE CONFORMS TO EIA-481 & EIA-541.



NOTES:

1. OUTLINE CONFORMS TO EIA-481.

Note: For the most current drawing please refer to IR website at http://www.irf.com/package/



Qualification Information[†]

		Automotive (per AEC-Q101) ††				
Qualificatio	n Level	Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.				
Moisture Sensitivity Level		D-PAK MSL1				
Machine Model		Class M4				
		AEC-Q101-002				
FOR	Human Body Model	Class H1C				
ESD		AEC-Q101-001				
	Class C5					
	Model	AEC-Q101-005				
RoHS Compliant		Yes				

- † Qualification standards can be found at International Rectifier's web site: http://www.irf.com/
- †† Exceptions to AEC-Q101 requirements are noted in the qualification report.



IMPORTANT NOTICE

Unless specifically designated for the automotive market, International Rectifier Corporation and its subsidiaries (IR) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or services without notice. Part numbers designated with the "AU" prefix follow automotive industry and / or customer specific requirements with regards to product discontinuance and process change notification. All products are sold subject to IR's terms and conditions of sale supplied at the time of order acknowledgment.

IR warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with IR's standard warranty. Testing and other quality control techniques are used to the extent IR deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

IR assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using IR components. To minimize the risks with customer products and applications, customers should provide adequate design and operating safeguards.

Reproduction of IR information in IR data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alterations is an unfair and deceptive business practice. IR is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of IR products or serviced with statements different from or beyond the parameters stated by IR for that product or service voids all express and any implied warranties for the associated IR product or service and is an unfair and deceptive business practice. IR is not responsible or liable for any such statements.

IR products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or in other applications intended to support or sustain life, or in any other application in which the failure of the IR product could create a situation where personal injury or death may occur. Should Buyer purchase or use IR products for any such unintended or unauthorized application, Buyer shall indemnify and hold International Rectifier and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that IR was negligent regarding the design or manufacture of the product.

IR products are neither designed nor intended for use in military/aerospace applications or environments unless the IR products are specifically designated by IR as military-grade or "enhanced plastic." Only products designated by IR as military-grade meet military specifications. Buyers acknowledge and agree that any such use of IR products which IR has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

IR products are neither designed nor intended for use in automotive applications or environments unless the specific IR products are designated by IR as compliant with ISO/TS 16949 requirements and bear a part number including the designation "AU". Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, IR will not be responsible for any failure to meet such requirements.

For technical support, please contact IR's Technical Assistance Center

http://www.irf.com/technical-info/

WORLD HEADQUARTERS:

233 Kansas St., El Segundo, California 90245

Tel: (310) 252-7105



Revision History

Date	Comments				
3/17/2014	Added "Logic Level Gate Drive" bullet in the features section on page 1				
	Updated data sheet with new IR corporate template				